

STPAC02F2

IPAD™

RF Detector for power amplifier control with internal temperature compensation

Main product characteristics

- 0.8 to 2.5 GHz frequency range
- Detection diode voltage drop compensation
- Temperature compensation
- Fast response time
- Low Power consumption
- Chip Scale device
- Low parasitic impedance
- Lead free package

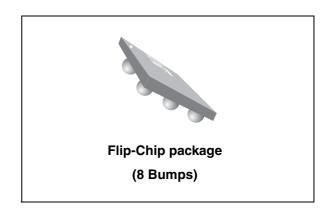
Description

The STPAC02F2 is an integrated RF detector for power control chain. It has been developed to convert the RF signal coming from the external coupler into a DC signal usable by the mobile digital stage. It is based on the use of two similar diodes, one assuming the signal detection while the second one is used to compensate the ambient temperature effect. A biasing stage suppresses the detection diode drop voltage effect. The use of the IPAD technology allows the RF front-end designer to save PCB area and to drastically suppress the parasitic inductances of the package.

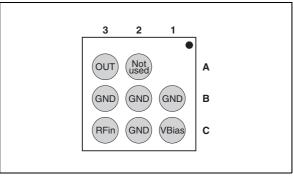
Target applications are cellular phones and PDA using GSM, DCS, PCS, AMPS, TDMA, CDMA and 800 MHz to 2100 MHz frequency ranges.

Benefits

■ The use of IPAD technology allows the RF front-end designer to save PCB area and to drastically suppress the parasitic inductances.



Pin configuration



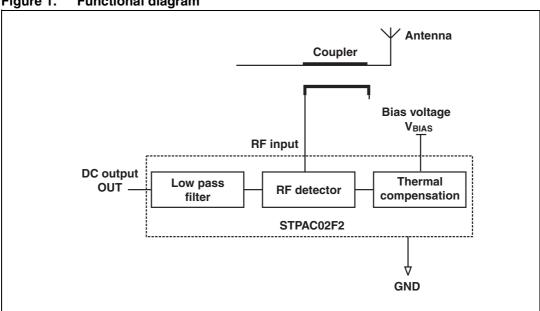
Order code

Part number	Marking		
STPAC02F2	RB		

Characteristics

Characteristics

Figure 1. **Functional diagram**



Absolute ratings $(T_{amb} = 25^{\circ} C)$ Table 1.

Symbol	Parameter and test conditions	Value	Unit
V _{BIAS}	Bias voltage	5	V
P _{RF}	RF power at the RF input	20	dbm
F _{OP}	Operating frequency range	0.8 to 2.5	GHz
V _{PP}	ESD level as per MIL-STD 883E method 3015.7 notice 8 (HBM)	250	V
T _{OP}	Operating temperature range	- 30 to + 85	°C
T _{STG}	Storage temperature range	- 55 to 150	°C

Electrical characteristics ($T_{amb} = 25^{\circ} C$) 1.1

Table 2. Parameters related to bias voltage

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V_{BIAS}	Operating bias voltage		2.3	2.8	3.3	٧
I _{BIAS}	Bias current	V _{BIAS} = 3.3 V		1.1	1.6	mA

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Table 3. Parameters related to detection function ($V_{BIAS} = 2.8 \text{ V}$, DC output load = 200 k Ω)

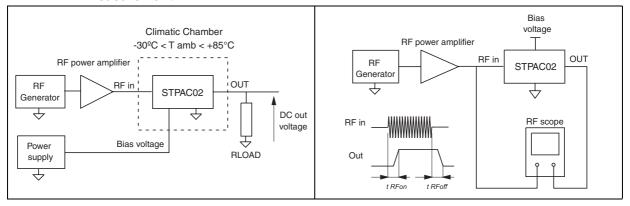
Symbol	Parameter Test conditions		Min	Тур	Max	Unit
		F = 1.75 GHz, P _{RF} = 10 dbm	0.63	0.69	0.75	
W	V _{DCout} DC output voltage (see <i>Figure 2</i> .)	F = 1.75 GHz, P _{RF} = - 20 dbm	0.20	0.22	0.24	V
▼ DCout		F = 0.9 GHz, P _{RF} = 10 dbm	0.69	0.75	0.83	V
	F = 0.9 GHz, P _{RF} = - 20 dbm	0.20	0.22	0.24		
ΔV_{DCout}	DC output voltage variation (see <i>Figure 2</i> .)	2.3 V < V _{BIAS} < 3.3 V, F = 1.85 GHz, P _{RF} =10 dbm		100		mV

Table 4. Parameters related to response time (V_{BIAS} = 2.8 V, DC output load = 200 k Ω)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t _{VBIAS}	Delay at V _{BIAS} ON (see <i>Figure 4</i> .)	V _{BIAS} from 0 to 3 V		1		
t _{RFon}	Delay at RF ON (see Figure 3.)	P _{RF} from 0 to 20 dbm		0.2		V
t _{RFoff}	Delay at RF OFF (see <i>Figure 3</i> .)	P _{RF} from 20 to 0 dbm		0.2		

Figure 2. V_{DC} output measurement circuit and temperature compensation measurement

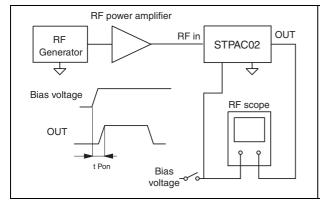
Figure 3. RF Power ON/OFF response time set-up



Characteristics STPAC02F2

Figure 4. Power supply turn ON response time

Figure 5. Temperature sensitivity versus RF Power in $(V_{BIAS} = 2.8 \text{ V}, Freq. = 900 \text{ MHz})$



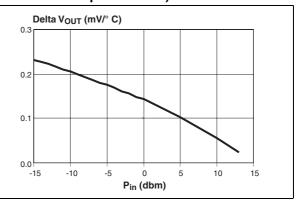
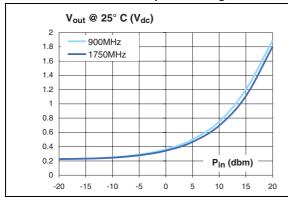


Figure 6. STPAC02 Output voltage at wide RF power range

Figure 7. Power detector sensitivity at wide RF power range



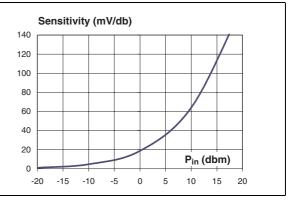
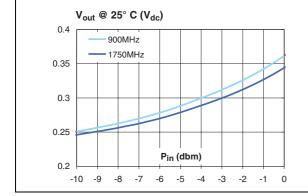
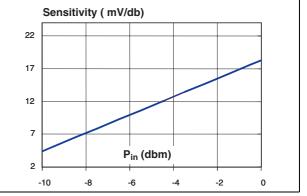


Figure 8. STPAC02 Output voltage at low RF power

Figure 9. Power detector sensitivity at low RF power





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2 Packaging information

Figure 10. Flip-Chip dimensions

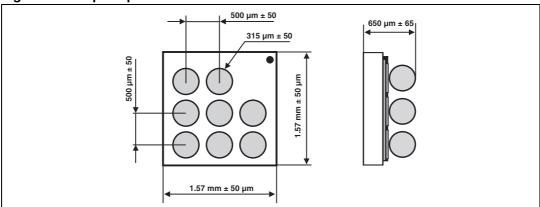


Figure 11. Foot print recommendations Figure 12. Marking

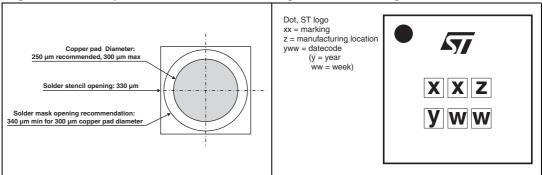
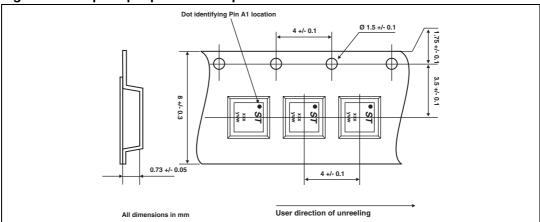


Figure 13. Flip-Chip tape and reel specification



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

3 Ordering information

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STPAC02F1	RB	Flip-Chip	3.3 mg	5000	Tape and reel

Note: More packing informations are available in the application notes:

AN1235: "Flip-Chip: Package description and recommendations for use"

AN1751: "EMI Filters: Recommendations and measurements"

4 Revision history

Date	Revision	Changes
16-May-2006	1	Initial release.

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